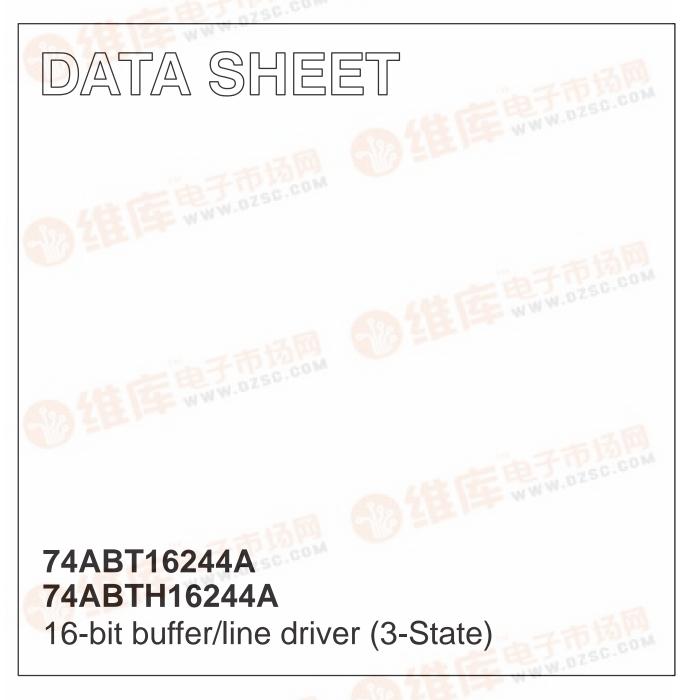
# G供应商 INTEGRATED CIRCUITS°CB打样工厂,24小时加急



Product specification Supersedes data of 1998 Feb 25 IC23 Data Handbook 1998 Oct 07







## 74ABT16244A 74ABTH16244A

#### **FEATURES**

- 16-bit bus interface
- Multiple V<sub>CC</sub> and GND pins minimize switching noise
- Power-up 3-State
- 3-State buffers
- Output capability: +64 mA/–32mA
- Live insertion/extraction permitted
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- 74ABTH16244A incorporates bus hold data inputs which eliminate the need for external pull up resistors to hold unused inputs
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs

#### DESCRIPTION

The 74ABT16244A high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT16244A device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ( $1\overline{OE}$ ,  $2\overline{OE}$ ,  $3\overline{OE}$ ,  $4\overline{OE}$ ), each controlling four of the 3-State outputs. Two options are available, 74ABT16244A which does not have the bus hold feature and 74ABTH16244A which incorporates the bus hold feature.

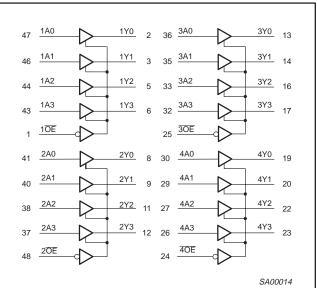
### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	$C_L = 50 pF; V_{CC} = 5V$	1.7 2.1	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	4	pF
C <sub>OUT</sub>	Output capacitance	$V_{O} = 0V \text{ or } V_{CC}$ ; 3-State	7	pF
I <sub>CCZ</sub>	Quiescent supply current	Outputs disabled; $V_{CC} = 5.5V$	450	μΑ
I <sub>CCL</sub>		Outputs low; $V_{CC} = 5.5V$	10	mA

#### **ORDERING INFORMATION**

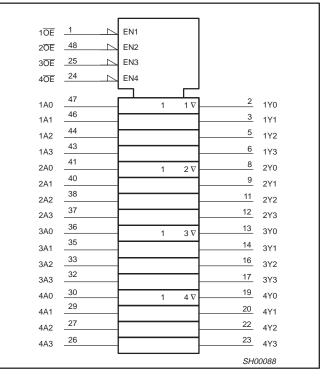
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ABT16244A DL	BT16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74ABT16244A DGG	BT16244A DGG	SOT362-1
48-Pin Plastic SSOP Type III	−40°C to +85°C	74ABH16244A DL	BH16244A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ABH16244A DGG	BH16244A DGG	SOT362-1

#### LOGIC SYMBOL



### 74ABT16244A 74ABTH16244A

#### LOGIC SYMBOL (IEEE/IEC)



### **PIN CONFIGURATION**

10E 1	48	2 <del>0E</del>
1Y0 2	47	1A0
1Y1 3	46	1A1
GND 4	45	GND
1Y2 5	44	1A2
1Y3 6	43	1A3
V <sub>CC</sub> 7	42	VCC
2Y0 8	41	2A0
2Y1 9	40	2A1
GND 10	39	GND
2Y2 11	38	2A2
2Y3 12	37	2A3
3Y0 13	36	3A0
3Y1 14	35	3A1
GND 15	34	GND
3Y2 16	33	3A2
3Y4 17	32	3A3
V <sub>CC</sub> 18	31	V <sub>CC</sub>
4Y0 19	30	4A0
4Y1 20	29	4A1
GND 21	28	GND
4Y2 22	27	4A2
4Y3 23	26	4A3
40E 24	25	3 <del>0E</del>
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#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION		
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 – 1A3, 2A0 – 2A3, 3A0 – 3A3, 4A0 – 4A3	Data inputs		
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 – 1Y3, 2Y0 – 2Y3, 3Y0 – 3Y3, 4Y0 – 4Y3	Data outputs		
1, 48 25, 24	1 <u>0E</u> , 2 <u>0E,</u> 3 <u>0E</u> , 4 <u>0E</u>	Output enables		
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)		
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage		

### **FUNCTION TABLE**

INP	OUTPUTS	
nOE	nAx	nYx
L	L	L
L	Н	н
н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care Z = High impedance "off" state

# 74ABT16244A 74ABTH16244A

#### ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-18	mA
VI	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
		output in Low state	128	
IOUT	DC output current	output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		–65 to 150	°C

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	BOL PARAMETER	LIM	UNIT	
STMBOL		MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-32	mA
I <sub>OL</sub>	Low-level output current		64	mA
Δt/Δv	Input transition rise or fall rate	0	10	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

## 74ABT16244A 74ABTH16244A

### **DC ELECTRICAL CHARACTERISTICS**

						LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS		Tai	T <sub>amb</sub> = +25°C			–40°C 85°C		
			Min	Тур	Max	Min	Max			
VIK	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18m$	A		-0.9	-1.2		-1.2	V	
		V <sub>CC</sub> = 4.5V; I <sub>OH</sub> = -3m	A; $V_I = V_{IL}$ or $V_{IH}$	2.5	2.9		2.5			
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 5.0V; I_{OH} = -3m$	A; $V_I = V_{IL}$ or $V_{IH}$	3.0	3.4		3.0		V	
		$V_{CC} = 4.5 V; I_{OH} = -32 r$	mA; V <sub>I</sub> = V <sub>IL</sub> or V <sub>IH</sub>	2.0	2.4		2.0			
V <sub>OL</sub>	Low-level output voltage	$V_{CC} = 4.5 V; I_{OL} = 64 m.$	A; $V_I = V_{IL}$ or $V_{IH}$		0.42	0.55		0.55	V	
l <sub>l</sub>	Input leakage current	V <sub>CC</sub> = 5.5V; V <sub>I</sub> = GND	or 5.5V		±0.01	±1.0		±1.0	μA	
	Input leakage current	$V_{CC} = 5.5V; V_I = V_{CC}$ or GND	Control pins		±0.01	±1		±1		
I	74ABTH16244A	$V_{CC} = 5.5V; V_{I} = V_{CC}$	Data Pins		0.01	1		1	μA	
		$V_{CC} = 5.5V; V_{I} = 0$	Data Pins		-2	-3		-5	1	
		$V_{CC} = 4.5 V; V_{I} = 0.8 V$	$V_{CC} = 4.5 V; V_{I} = 0.8 V$				50		μΑ	
I <sub>HOLD</sub>	Bus Hold current A inputs <sup>4</sup> 74ABTH16244A	$V_{CC} = 4.5V; V_{I} = 2.0V$		-75			-75			
		$V_{CC} = 5.5V; V_1 = 0 \text{ to } 5.5V$		±500						
I <sub>OFF</sub>	Power-off leakage current	$V_{CC}$ = 0.0V; $V_{O}$ or $V_{I}$ $\leq$	$V_{CC}$ = 0.0V; $V_O$ or $V_I \leq 4.5V$		±5.0	±100		±100	μΑ	
I <sub>PU</sub> /I <sub>PD</sub>	Power-up/down 3-State output current	$\begin{array}{l} V_{\underline{CC}} = 2.0 \text{V}; \ \text{V}_{\underline{O}} = 0.5 \text{V} \\ \text{V}_{\underline{OE}} = \text{V}_{\underline{CC}} \end{array}$	$V_{\underline{CC}}$ = 2.0V; $V_{O}$ = 0.5V; $V_{I}$ = GND or $V_{CC};$ $V_{OE}$ = $V_{CC}$		±5.0	±50		±50	μΑ	
I <sub>OZH</sub>	3-State output High current	$V_{CC} = 5.5 V; V_{O} = 5.5 V$	; $V_{I} = V_{IL} \text{ or } V_{IH}$		0.1	10		10	μA	
I <sub>OZL</sub>	3-State output Low current	$V_{CC} = 5.5 V; V_{O} = 0.0 V$	; $V_{I} = V_{IL}$ or $V_{IH}$		-0.1	-10		-10	μΑ	
I <sub>CEX</sub>	Output High leakage current	V <sub>CC</sub> = 5.5V; V <sub>O</sub> = 5.5V	; $V_I = GND \text{ or } V_{CC}$		5.0	50		50	μΑ	
Ι <sub>Ο</sub>	Output current <sup>1</sup>	$V_{CC} = 5.5 V; V_{O} = 2.5 V$		-50	-100	-180	-50	-180	mA	
I <sub>CCH</sub>		V <sub>CC</sub> = 5.5V; Outputs Hi	gh, $V_I = GND$ or $V_{CC}$		0.45	1.0		1.0	mA	
I <sub>CCL</sub>	Quiescent supply current <sup>3</sup>	$V_{CC}$ = 5.5V; Outputs Lo	ow, $V_I = GND$ or $V_{CC}$		10	19		19	mA	
I <sub>CCZ</sub>		$V_{CC}$ = 5.5V; Outputs 3-State; V <sub>I</sub> = GND or V <sub>CC</sub>			0.45	1.0		1.0	μA	
		Outputs enabled, one data input at 3.4V, other inputs at $V_{CC}$ or GND; $V_{CC}$ = 5.5V		Outputs enabled, one data input at 3.4V, other inputs at V <sub>CC</sub> or GND; $V_{CC} = 5.5V$		100	250		250	
$\Delta I_{CC}$	Additional supply current per input pin <sup>2, 3</sup>	Outputs disabled, one other inputs at $V_{CC}$ or $\theta$	data input at 3.4V, GND; V <sub>CC</sub> = 5.5V		100	250		250	μA	
		Control pins, outputs di input at 3.4V, other input $V_{CC} = 5.5V$	isabled, one enable uts at $V_{CC}$ or GND;		100	250		250		

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This is the increase in supply current for each input at 3.4V.
This data sheet limit may vary among suppliers.

4. This is the bus hold overdrive current required to force the input to the opposite logic state.

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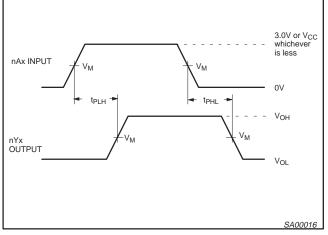
#### **AC CHARACTERISTICS**

GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ 

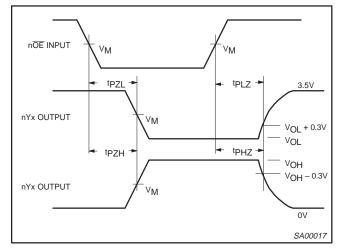
					LIMITS			
SYMBOL	PARAMETER	WAVEFORM	T V	<sub>amb</sub> = +25°0 V <sub>CC</sub> = +5.0V		$T_{amb} = -40^{\circ}$ $V_{CC} = +5^{\circ}$	°C to +85°C .0V ±0.5V	UNIT
			MIN	TYP	MAX	MIN	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	1	1.1 1.3	1.7 2.1	2.6 2.9	1.1 1.3	2.8 3.4	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.6 2.3	2.7 3.5	3.7 4.0	1.6 2.3	4.5 4.8	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low level	2	2.0 1.6	3.0 2.4	4.0 3.2	2.0 1.6	4.6 4.1	ns

### AC WAVEFORMS

 $V_{M}$  = 1.5V,  $V_{IN}$  = GND to 3.0V



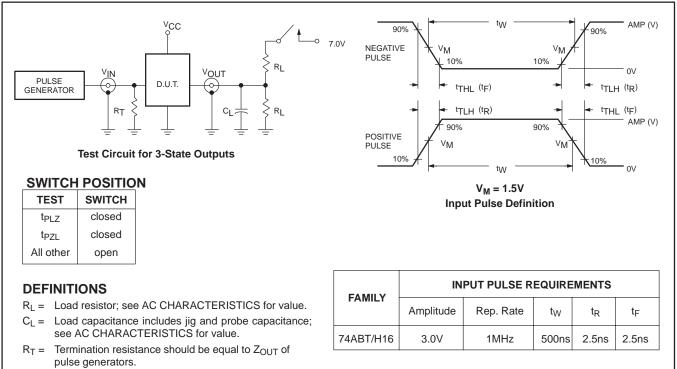




Waveform 2. 3-State Output Enable and Disable Times

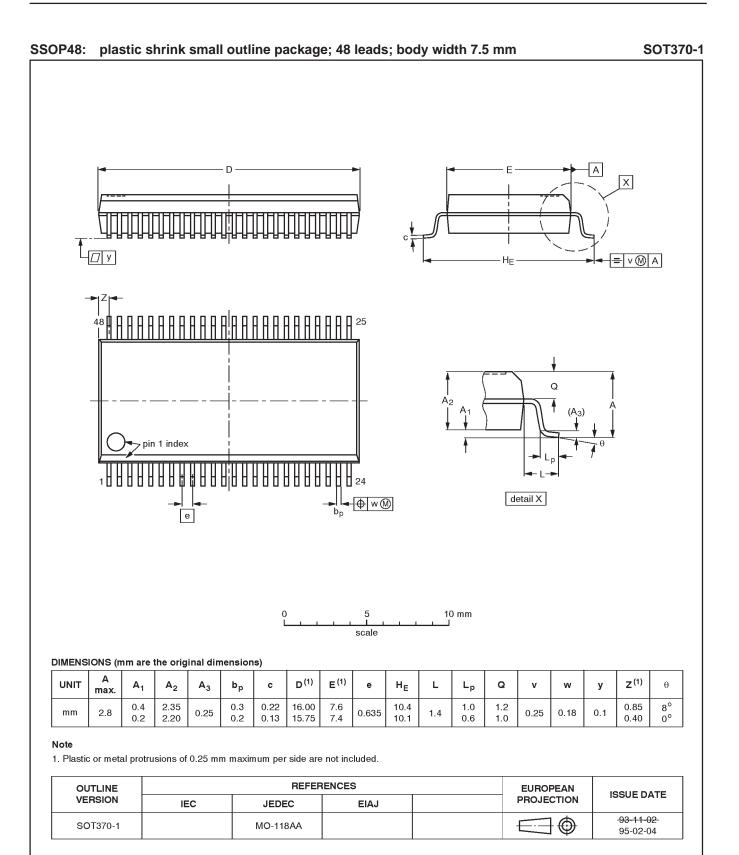
### 74ABT16244A 74ABTH16244A

### **TEST CIRCUIT AND WAVEFORMS**

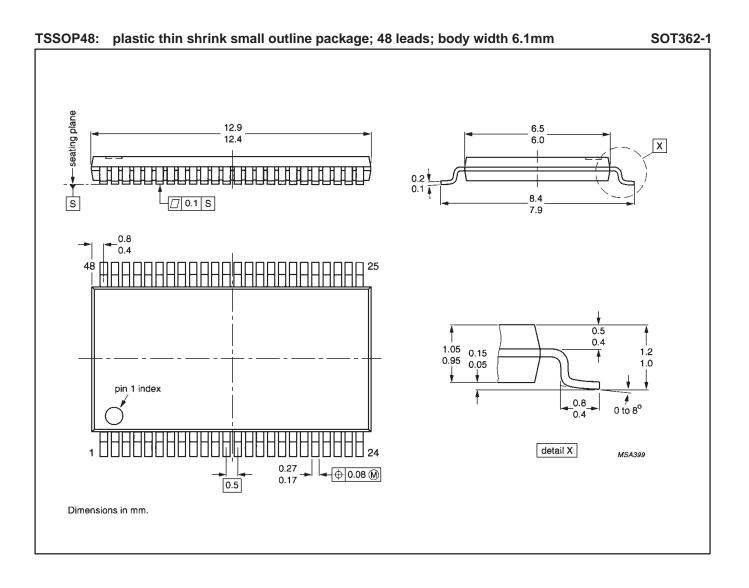


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### 74ABT16244A 74ABTH16244A



# 74ABT16244A 74ABTH16244A



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#### Data sheet status

Data sheet status	Product status	Definition <sup>[1]</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

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